CLAIMS

- 1. An organic light-light conversion device comprising:
- a light sensing unit having a layer including a photo-conductive organic semiconductor that causes a photo-current multiplication phenomenon by light irradiation, and
- a light emitting unit having a layer including an electroluminescent organic semiconductor that emits light by current injection, characterized in that
- at least one of the photo-conductive organic semiconductor and the electroluminescent organic semiconductor is a polymer semiconductor.
- 2. The organic light-light conversion device according to claim 1, wherein the photo-conductive organic semiconductor is a polymer semiconductor.
- 3. The organic light-light conversion device according to claim 1, wherein the electroluminescent organic semiconductor is a polymer semiconductor.
- 4. The organic light-light conversion device according to any one of claims 1 to 3, wherein the photo-conductive organic semiconductor and the electroluminescent organic semiconductor are polymer semiconductors.
- 5. The organic light-light conversion device according to any one of claims 1 to 4, comprising:
 - a) a light sensing unit having a layer

including the photo-conductive organic semiconductor,

- b) a light emitting unit having a layer including the electroluminescent organic semiconductor placed on a different location from the light sensing unit on the same substrate, and
- c) a conductive layer connecting the light sensing unit to the light emitting unit laid on the same substrate.
- 6. The organic light-light conversion device according to claim 5, wherein a light shielding member is provided between the light sensing unit and light emitting unit.
- 7. The organic light-light conversion device according to claim 5, wherein a translucent member having a transmittance that suppresses but does not completely shield the flow of feedback light into the light sensing unit is provided between the light sensing unit and the light emitting unit.
- 8. The organic light-light conversion device according to any one of claims 1 to 4, wherein the light sensing unit having a layer including the photoconductive organic semiconductor is integrally laminated with the light emitting unit having a layer including the electroluminescent organic semiconductor.
- 9. The organic light-light conversion device according to any one of claims 1 to 8, wherein the polymer semiconductor contains one or more repeating units represented by the following Formula (1):

$$\left\{ \left(Ar_{1} \right)_{\mathbf{m}} \left(X_{1} \right)_{\mathbf{n}} \right\}_{\mathbf{p}} \left(Ar_{2} \right)_{\mathbf{q}} \tag{1}$$

wherein Ar_1 and Ar_2 each independently represent an arylene group or a divalent heterocyclic group; X1 represents $-CR_1=CR_2-$, $-C\equiv C-$ or $-N(R_3)-$; R_1 and R_2 each independently represent a hydrogen atom, an alkyl group, an aryl group, a monovalent heterocyclic group, a carboxyl group, a substituted carboxyl group or a cyano group; R3 represents a hydrogen atom, an alkyl group, an aryl group, a monovalent heterocyclic group, an arylalkyl group or a substituted amino group; m, n and q each independently represent an integer of 0 or 1; p represents an integer of 0 to 2; and m + n and p + nq are each 1 or more, provided that Ar_1 , X_1 , R_1 , R_2 and R_3 , if they are each multiple, can be respectively identical or different, and has a polystyrene-converted number average molecular weight of 1×10^3 to 1×10^8 . The organic light-light conversion device according to any one of claims 1 to 9, wherein the layer including the photo-conductive organic semiconductor and/or the layer including the electroluminescent organic semiconductor contains two or more polymer semiconductors containing one or more repeating units represented by Formula (1).

11. An image intensifier characterized by

comprising a plurality of the organic light-light conversion devices according to any one of claims 1 to 10 arranged.

12. A light sensor characterized by comprising the organic light-light conversion device according to any one of claims 1 to 10, and a means to measure and output a voltage applied to both ends of the layer including the electroluminescent organic semiconductor.